

# RECTIFIER ASSEMBLIES

Single Phase Bridges, 25 Amp,  
Military Approved

JAN SPA25  
JAN SPB25  
JAN SPC25  
JAN SPD25

## FEATURES

- Qualified to MIL-S-19500/446
- Current Rating: to 25A
- PIV: from 100 to 600V
- Surge Ratings of 150A
- Only Fused-in-Glass Diodes Used
- Controlled Avalanche Characteristics
- Aluminum Heat Sink Case, Electrically Insulated

## DESCRIPTION

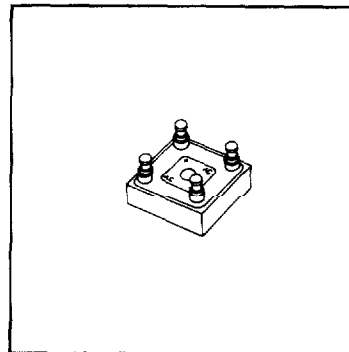
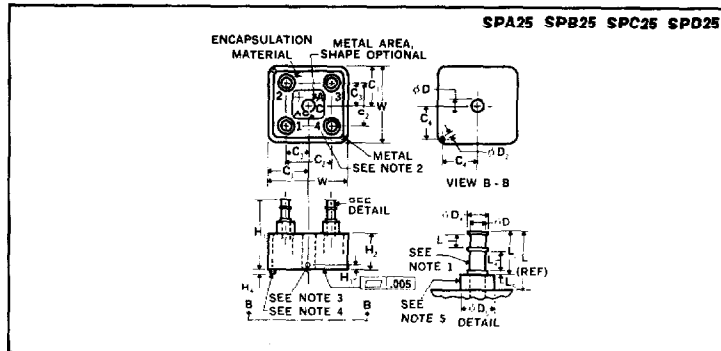
This series of military high-current single-phase bridges offer the utmost in reliability as required in military system designs. This series is assembled with diodes which have been subjected to 100% screening tests.

## ABSOLUTE MAXIMUM RATINGS

Peak Inverse Voltage	100 to 600V
Maximum Average D.C. Output Current	
@ $T_c = 55^\circ\text{C}$	25A
@ $T_c = 100^\circ\text{C}$	15A
Non-Repetitive Sinusoidal Surge (8.3ms)	
@ $T_c = 55^\circ\text{C}$	150A
Operating and Storage Temperature Range, $T_c$	$-65^\circ\text{C}$ to $+150^\circ\text{C}$
Thermal Resistance Junction to Ambient	$20^\circ\text{C/W}$
Junction to Case	$2.5^\circ\text{C/W}$

Ltr	Dimensions			
	INCHES		MILLIMETERS	
	MIN.	MAX.	MIN.	MAX.
C <sub>1</sub>	.552	.572	14.02	14.53
C <sub>2</sub>	.624	.760	15.85	19.30
C <sub>3</sub>	.312	.380	7.92	9.65
C <sub>4</sub>	.495	.512	12.57	13.00
$\phi D_1$	.189	.195	4.80	4.95
$\phi D_2$	.057	.067	1.45	1.70
$\phi D_3$	.108	.118	2.74	3.00
$\phi D_4$	.141	.151	3.58	3.84
$\phi D_5$	.225	.235	5.72	5.97
H <sub>1</sub>	.669	1.060	17.53	26.92
H <sub>2</sub>	.300	.500	7.62	12.70
H <sub>3</sub>	.040	.060	1.02	1.52
H <sub>4</sub>	.042	.062	1.07	1.57
L <sub>1</sub>	.370	.560	9.40	14.22
L <sub>2</sub>	.307	.365	7.80	9.27
L <sub>3</sub>	.089	.099	2.26	2.49
L <sub>4</sub>	.132	.142	3.35	3.61
L <sub>5</sub>	.026	.036	.66	.92
W	1.104	1.144	28.04	29.06

## MECHANICAL SPECIFICATIONS



### NOTES:

1. Terminals shall be hot tin dipped or silver plated.
2. Polarity shall be marked on terminal side of device.
3. Point at which  $T_c$  is read (must be in metal part of case).
4. Locating pin shall be adjacent to positive terminal.
5. Insulating sleeve shall be alumina ( $Al_2O_3$ ) or equivalent.

**Microsemi Corp.**  
**Watertown**  
The diode experts

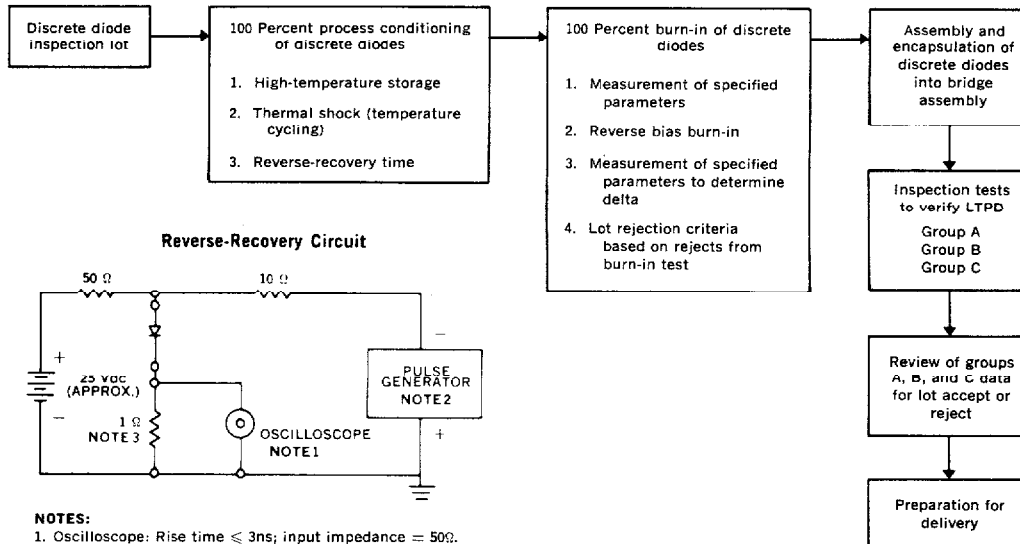
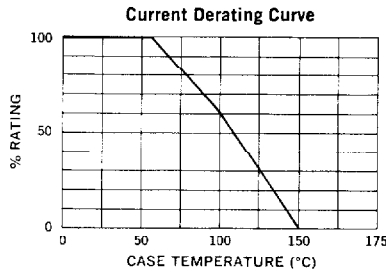
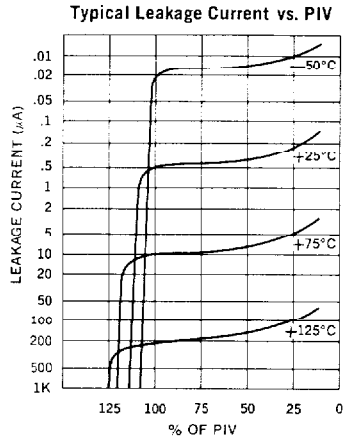
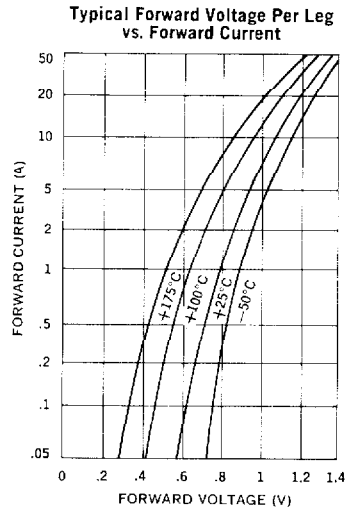
Electrical Specifications (at 25°C unless noted)

Type	PIV Per Leg	Peak Forward Voltage Drop*		Maximum Reverse Recovery Time†	Maximum Leakage Current Per Leg @ PIV	
		Minimum	Maximum		T <sub>C</sub> = 25°C	T <sub>C</sub> = 100°C
	Volts			μS	μA	μA
JAN SPA25	100	0.9V @ 39A(pk)	1.4V	2	2	150
JAN SPB25	200					
JAN SPC25	400					
JAN SPD25	600					

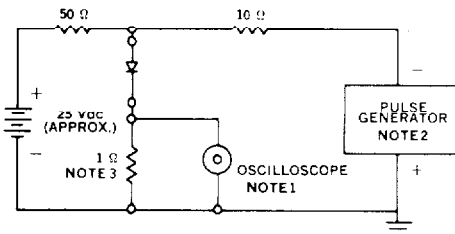
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\*Peak forward voltage drop is measured at a pulse width of 8.3ms.

†Measured in a reverse recovery circuit switching from 0.5A forward to 1.0A reverse current recovery to 0.5A.



Reverse-Recovery Circuit



- NOTES:**
- Oscilloscope: Rise time ≤ 3ns; input impedance = 50Ω.
  - Pulse Generator: Rise time ≤ 8ns; source impedance 10Ω.
  - Current viewing resistor, non-inductive, coaxial recommended.